

COMMUNICATIONS CIRCUITS READY-REFERENCE

JOHN MARKUS

COMMUNICATIONS CIRCUITS READY-REFERENCE



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COMMUNICATIONS CIRCUITS READY-REFERENCE

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Preface

Communications Circuits Ready-Reference is one of five books in the Ready-Reference series. These books are the product of cover-to-cover searching of back issues of U.S. and foreign electronics periodicals, the published literature of electronics manufacturers, and recent electronics books, together filling well over 100 feet of shelving. This same search would take weeks or even months at a large engineering library, plus the time required to write for manufacturer literature and locate elusive sources.

Each circuit has type numbers or values of all significant components, an identifying title, a concise description, performance data, and suggested applications. At the end of each description is a citation giving the title of the original article or book, its author, and the exact location of the circuit in the original source.

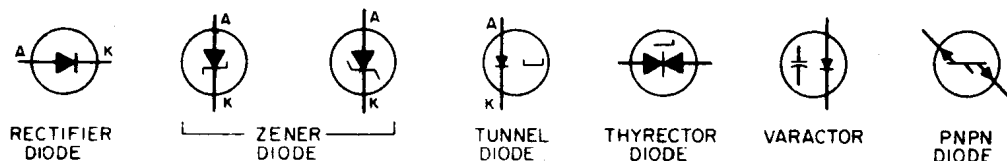
To find a desired circuit quickly, start with the alphabetically arranged table of contents at the front of the book. Note the chapters most likely to contain the desired type of circuit, and look in these first. If a quick scan does not locate the exact circuit desired, use the index at the back of the book. Here the circuits are indexed in depth under the different names by which they may be known. Cross-references in the index aid searching. The author index will often help find related circuits after one potentially useful circuit is found, because authors tend to specialize in certain circuits.

To the original publications cited and their engineering authors and editors, should go major credit for making this book possible. The diagrams have been reproduced directly from the original source articles, by permission of the publisher in each case.

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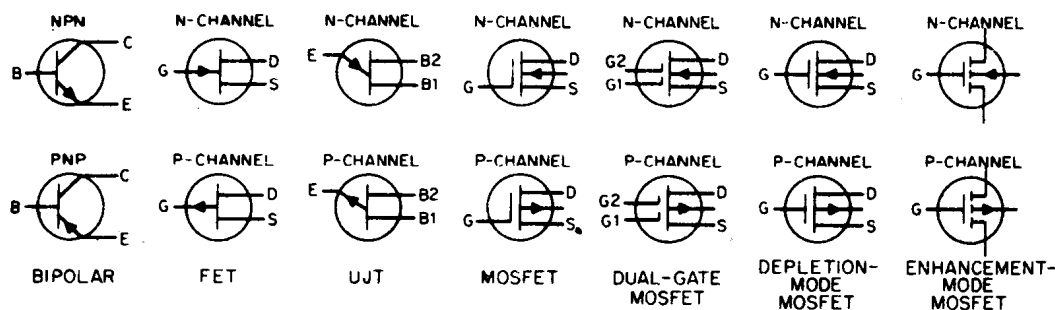
Semiconductor Symbols Used

DIODES:

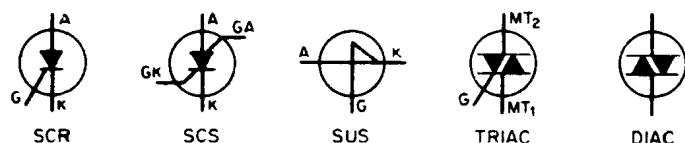


E = EMITTER
B = BASE
C = COLLECTOR
G = GATE
A = ANODE
K = CATHODE
D = DRAIN
S = SOURCE
MT = MAIN TERMINAL

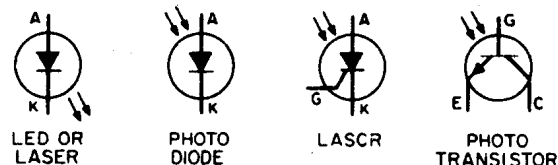
TRANSISTORS:



POWER CONTROL DEVICES:



OPTOELECTRONIC DEVICES:



The commonest forms of the basic semiconductor symbols are shown here. Leads are identified where appropriate, for convenient reference. Minor variations in symbols, particularly those from foreign sources, can be recognized by comparing with these symbols while noting positions and directions of solid arrows with respect to other symbol elements.

Omission of the circle around a symbol has no significance. Arrows are sometimes drawn open instead of solid. Thicker lines and open rectangles in some symbols on diagrams have no significance. Orientation of symbols is unimportant; artists choose the position that is most convenient for making connections to other parts of the circuit. Arrow lines outside optoelectronic symbols indicate the direction of light rays.

On some European diagrams, the position of the letter k gives the location of the decimal point for a resistor value in kilohms. Thus, 2k2 is 2.2K or 2,200 ohms. Similarly, a resistance of 1R5 is 1.5 ohms, 1M2 is 1.2 megohms, and 3n3 is 3.3 nanofarads.

Substitutions can often be made for semiconductor and IC types specified on diagrams. Newer components, not available when the original source article was published, may actually improve the performance of a particular circuit. Electrical char-

acteristics, terminal connections, and such critical ratings as voltage, current, frequency, and duty cycle, must of course be taken into account if experimenting without referring to substitution guides.

Semiconductor, integrated-circuit, and tube substitution guides can usually be purchased at electronic parts supply stores.

Not all circuits give power connections and pin locations for ICs, but this information can be obtained from manufacturer data sheets. Alternatively, browsing through other circuits may turn up another circuit on which the desired connections are shown for the same IC.

When looking down at the top of an actual IC, numbering normally starts with 1 for the first pin *counterclockwise* from the notched or otherwise marked end and continues sequentially. The highest number is therefore next to the notch on the other side of the IC, as illustrated in the sketches below. (*Actual positions* of pins are rarely shown on schematic diagrams.)



Abbreviations Used

A	ampere	CRO	cathode-ray oscilloscope	F	farad
AC	alternating current	CROM	control and read-only memory	°F	degree Fahrenheit
AC/DC	AC or DC	CRT	cathode-ray tube	FET	field-effect transistor
A/D	analog-to-digital	CT	center tap	FIFO	first-in first-out
ADC	analog-to-digital converter	CW	continuous wave	FM	frequency modulation
A/D, D/A	analog-to-digital, or digital-to-analog	D/A	digital-to-analog	4PDT	four-pole double-throw
ADP	automatic data processing	DAC	digital-to-analog converter	4PST	four-pole single-throw
AF	audio frequency	dB	decibel	FS	full scale
AFC	automatic frequency control	dBc	C-scale sound level in decibels	FSK	frequency-shift keying
AFSK	audio frequency-shift keying	dBm	decibels above 1 mW	ft	foot
AFT	automatic fine tuning	dBV	decibels above 1 V	ft/min	foot per minute
AGC	automatic gain control	DC	direct current	ft/s	foot per second
Ah	ampere-hour	DC/DC	DC to DC	ft²	square foot
ALU	arithmetic-logic unit	DCTL	direct-coupled transistor logic	F/V	frequency-to-voltage
AM	amplitude modulation	diac	diode AC switch	F/V, V/F	frequency-to-voltage, or voltage-to-frequency
AM/FM	AM or FM	DIP	dual in-line package	G	giga- (10 ⁹)
AND	type of logic circuit	DMA	direct memory access	GHz	gigahertz
AVC	automatic volume control	DMM	digital multimeter	G-M tube	Geiger-Mueller tube
b	bit	DPDT	double-pole double-throw	h	hour
BCD	binary-coded decimal	DPM	digital panel meter	H	henry
BFO	beat-frequency oscillator	DPST	double-pole single-throw	HF	high frequency
b/s	bit per second	DSB	double sideband	HFO	high-frequency oscillator
C	capacitance; capacitor	DTL	diode-transistor logic	hp	horsepower
°C	degree Celsius; degree Centigrade	DTL/TTL	DTL or TTL	Hz	hertz
CATV	cable television	DUT	device under test	IC	integrated circuit
CB	citizens band	DVM	digital voltmeter	IF	intermediate frequency
CCD	charge-coupled device	DX	distance reception; distant	IGFET	insulated-gate FET
CCTV	closed-circuit television	EAROM	electrically alterable ROM	IMD	intermodulation distortion
cm	centimeter	EBCDIC	extended binary-coded decimal interchange code	IMPATT	impact avalanche transit time
CML	current-mode logic	ECG	electrocardiograph	in	inch
CMOS	complementary MOS	ECL	emitter-coupled logic	in/s	inch per second
CMR	common-mode rejection	EDP	electronic data processing	in²	square inch
CMRR	common-mode rejection ratio	EKG	electrocardiograph	I/O	input/output
cm²	square centimeter	EMF	electromotive force	IR	infrared
coax	coaxial cable	EMI	electromagnetic interference	JFET	junction FET
COHO	coherent oscillator	EPROM	erasable PROM	k	kilo- (10 ³)
COR	carrier-operated relay	ERP	effective radiated power	K	kilohm (10 ³ ohms); kelvin
COS/MOS	complementary-symmetry MOS (same as CMOS)	ETV	educational television	kA	kiloampere
CPU	central processing unit	eV	electronvolt	kb	kilobit
CR	cathode ray	EVR	electronic video recording	keV	kiloelectronvolt
		EXCLUSIVE-OR	type of logic circuit	.kH	kilohenry
		EXCLUSIVE-NOR	type of logic circuit	kHz	kilohertz
				km	kilometer
				kV	kilovolt
				kVA	kilovoltampere
				kW	kilowatt
				kWh	kilowatthour
				L	inductance; inductor
				LASCR	light-activated SCR

LASCS	light-activated SCS	NMOS	N-channel MOS	QRP	low-power amateur radio
LC	inductance-capacitance	NOR	type of logic circuit	R	resistance; resistor
LCD	liquid crystal display	NPN	negative-positive-negative	RAM	random-access memory
LDR	light-dependent resistor	NPNP	negative-positive-negative-positive	RC	resistance-capacitance
LED	light-emitting diode	NRZ	nonreturn-to-zero	RF	radio frequency
LF	low frequency	NRZI	nonreturn-to-zero-inverted	RFI	radio-frequency interference
LIFO	last-in first-out	ns	nanosecond	RGB	red/green/blue
lm	lumen	NTSC	National Television System Committee	RIAA	Recording Industry Association of America
LO	local oscillator	nV	nanovolt	RLC	resistance-inductance-capacitance
logamp	logarithmic amplifier	nW	nanowatt	RMS	root-mean-square
LP	long play	OEM	original equipment manufacturer	ROM	read-only memory
LSB	least significant bit	opamp	operational amplifier	rpm	revolution per minute
LSI	large-scale integration	OR	type of logic circuit	RTL	resistor-transistor logic
m	meter; milli- (10^{-3})	p	pico- (10^{-12})	RTTY	radioteletype
M	mega- (10^6); meter (instrument); motor	P	peak; positive	RZ	return-to-zero
mA	milliampere	pA	picoampere	s	second
Mb	megabit	PA	public address	SAR	successive-approximation register
MF	medium frequency	PAL	phase-alternation line	SAW	surface acoustic wave
mH	millihenry	PAM	pulse-amplitude modulation	SCA	Subsidiary Communications Authorization
MHD	magnetohydro-dynamics	PC	printed circuit	scope	oscilloscope
MHz	megahertz	PCM	pulse-code modulation	SCR	silicon controlled rectifier
mi	mile	PDM	pulse-duration modulation	SCS	silicon controlled switch
mike	microphone	PEP	peak envelope power	S-meter	signal-strength meter
min	minute	pF	picofarad	S/N	signal-to-noise
mm	millimeter	PF	power factor	SNR	signal-to-noise ratio
modem	modulator-demodulator	phono	phonograph	SPDT	single-pole double-throw
mono	monostable	PIN	positive-intrinsic-negative	SPST	single-pole single-throw
MOS	metal-oxide semiconductor	PIV	peak inverse voltage	SSB	single sideband
MOSFET	metal-oxide semiconductor FET	PLL	phase-locked loop	SSI	small-scale integration
MOST	metal-oxide semiconductor transistor	PM	permanent magnet; phase modulation	SSTV	slow-scan television
MPU	microprocessing unit	PMOS	P-channel MOS	SW	shortwave
ms	millisecond	PN	positive-negative	SWL	shortwave listener
MSB	most significant bit	PNP	positive-negative-positive	SWR	standing-wave ratio
MSI	medium-scale integration	PNP	positive-negative-positive-negative	sync	synchronizing
m ²	square meter	pot	potentiometer	T	tera- (10^{12})
μ	micro- (10^{-6})	P-P	peak-to-peak	TC	temperature coefficient
μ A	microampere	PPI	plan-position indicator	THD	total harmonic distortion
μ F	microfarad	PPM	parts per million; pulse-position modulation	TR	transmit-receive
μ H	microhenry	preamp	preamplifier	TRF	tuned radio frequency
μ m	micrometer	PRF	pulse repetition frequency	triac	triode AC semiconductor switch
μ P	microprocessor	PROM	programmable ROM	TTL	transistor-transistor logic
μ s	microsecond	PRR	pulse repetition rate		
μ V	microvolt	ps	picosecond		
μ W	microwatt	PSK	phase-shift keying		
mV	millivolt	PTT	push to talk		
MVBR	multivibrator	PUT	programmable UJT		
mW	milliwatt	pW	picowatt		
n	nano- (10^{-9})	PWM	pulse-width modulation		
N	negative	Q	quality factor		
nA	nanoampere				
NAB	National Association of Broadcasters				
NAND	type of logic circuit				
nF	nanofarad				
nH	nanohenry				

TTY	teletypewriter	V	volt	VSWR	voltage standing-wave ratio
TV	television	VA	voltampere	VTR	videotape recording
TVI	television interference	VAC	volts AC	VTVM	vacuum-tube voltmeter
TVT	television typewriter	VCO	voltage-controlled oscillator	VU	volume unit
TWX	teletypewriter exchange service	VDC	volts DC	VVC	voltage-variable capacitor
UART	universal asynchronous receiver-transmitter	V/F	voltage-to-frequency	VXO	variable-frequency crystal oscillator
UHF	ultrahigh frequency	VFO	variable-frequency oscillator	W	watt
UJT	unijunction transistor	VHF	very high frequency	Wh	watthour
UPC	universal product code	VLF	very low frequency	WPM	words per minute
UPS	uninterruptible power system	VMOS	vertical metal-oxide semiconductor	WRMS	watts RMS
		VOM	volt-ohm-milliammeter	Ws	wattsecond
		VOX	voice-operated transmission	Z	impedance
		VRMS	volts RMS		

Abbreviations on Diagrams. Some foreign publications, including *Wireless World*, shorten the abbreviations for units of measure on diagrams. Thus, μ after a capacitor value represents μF , n is nF, and p is pF. With resistor values, k is thousand ohms, M is megohms, and absence of a unit of measure is ohms. For a decimal value, the letter for the unit of measure is sometimes placed at the location of the decimal point. Thus, 3k3 is 3.3 kilohms or 3,300 ohms, 2M2 is 2.2 megohms, $4\mu7$ is $4.7 \mu\text{F}$, $0\mu1$ is $0.1 \mu\text{F}$, and $4n7$ is 4.7 nF .

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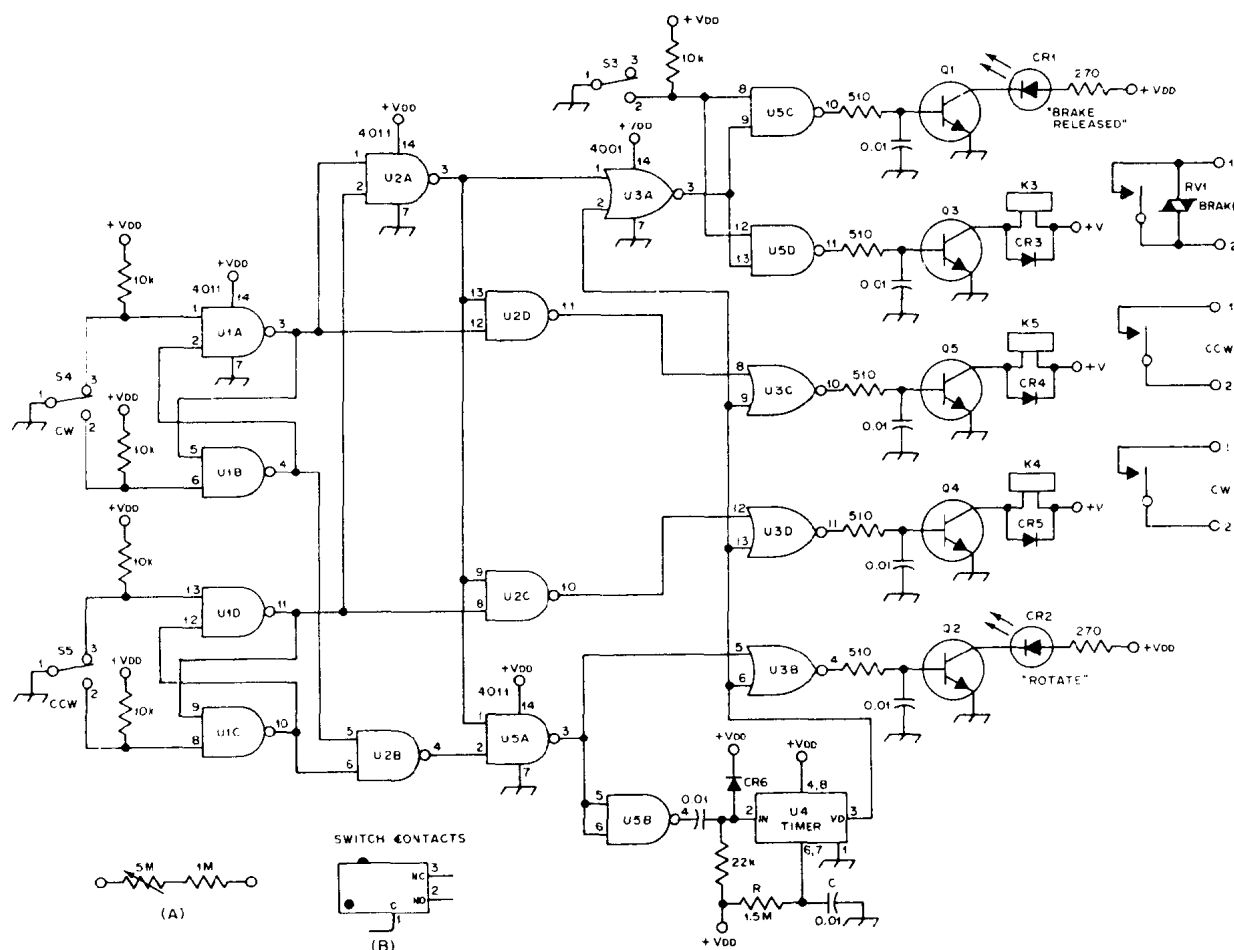
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CHAPTER 1

Antenna Circuits

Includes circuits for measuring and adjusting VSWR, field strength, earth conductivity for grounds, and impedance, as well as antenna motor controls, radio direction finders, sferics receiver, active antennas, RF attenuators, remote antenna switching systems, RF magnetometer, and far-field signal sources for tuning beam antennas. See also Receiver, Transceiver, and Transmitter chapters.



CR1, CR2 - Light-emitting diode, Motorola type MLED600 or equiv.
CR3-CR6, incl. - Silicon signal diode, 1N914 or equiv.
K3-K5, incl. - Switching relay, 12 V dc,

1200 ohms, 10 mA; contact rating 1 A; 125 V ac; Radio Shack 275-003 or equiv.
Q1-Q5, incl. - Silicon npn transistor, 2N3904 or equiv.
RV1 - Varistor, GE 750 or equiv.

U1, U2, U5 - CMOS quad NAND-gate IC, RCA CD 4011A or equiv.
U3 - CMOS quad NOR-gate IC, RCA CD-4001A, or equiv.
U4 - Timer IC, 555 or equiv.

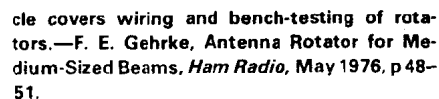
DELAYED BRAKE—Protects antenna rotator on high tower from damage by delaying brake action automatically after rotation and by disabling direction-selector switches so antenna system coasts to stop before rotation can begin

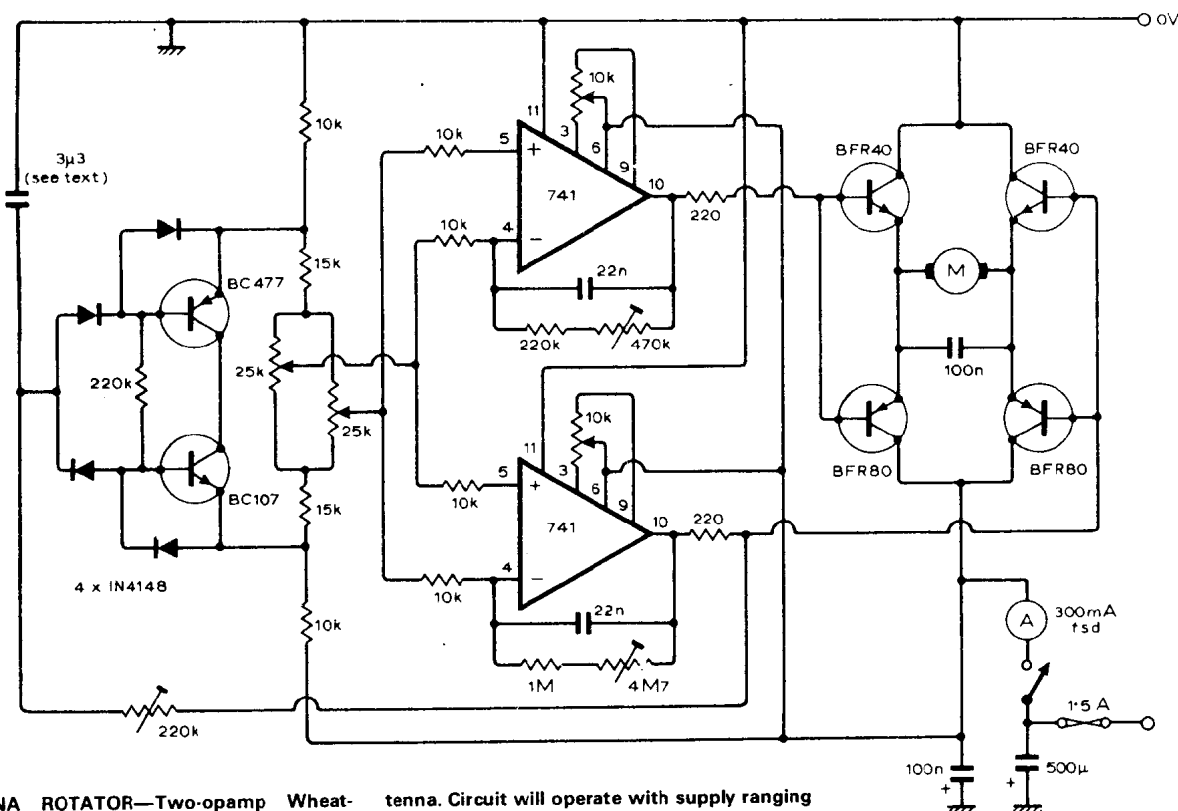
in other direction. For about 3-s delay in timer U4, use 2.2 megohms for R and 1 μ F for C instead of values shown. RV1 is commonly listed as V150LA20A by GE. S3-S5 are original brake release and direction switches in CDE Ham-II

rotor system. Article covers construction and installation, including modifications needed in control unit.—A. B. White, A Delayed Brake Release for the Ham-II, QST, Aug. 1977, p 14-16.

S1 POSITIONS

A	= 0 dB
B	= 10 dB
C	= 20 dB
D	= 30 dB
E	= 40 dB

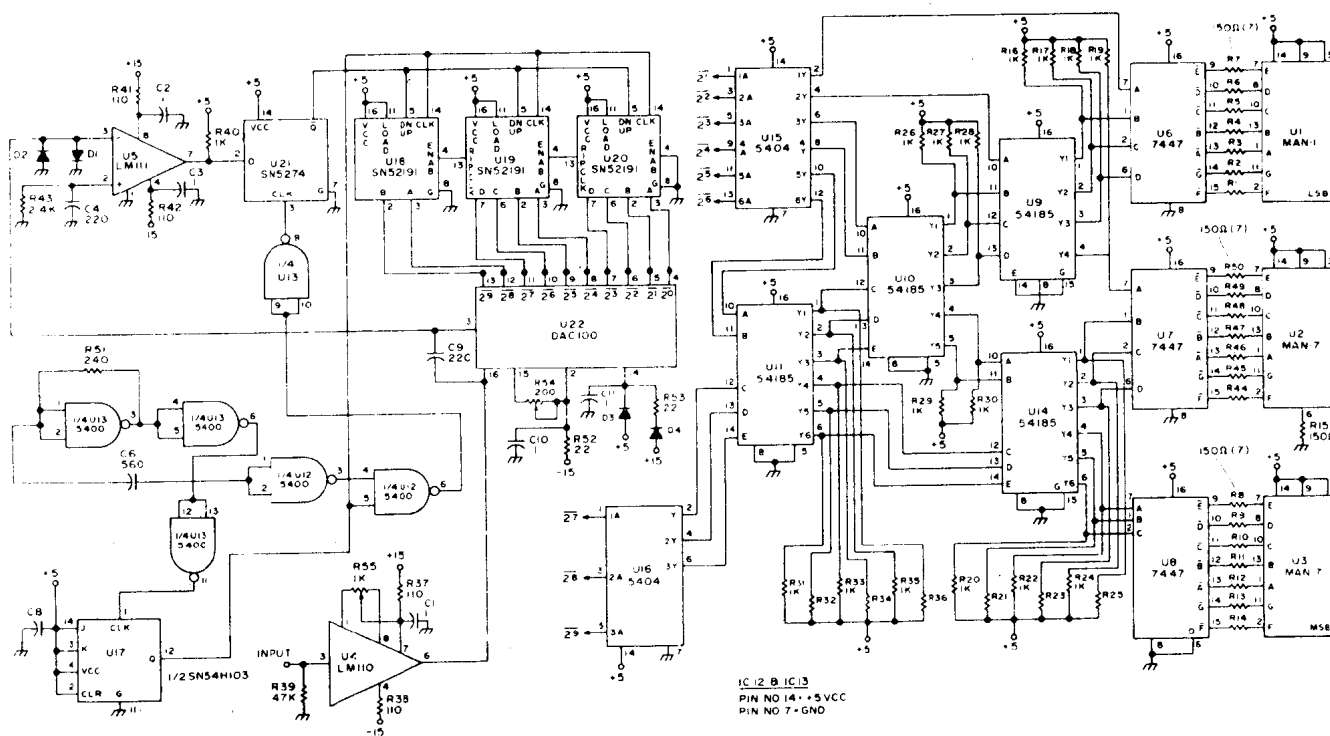




ANTENNA ROTATOR—Two-opamp Wheatstone bridge provides positive and negative error signals to give proportional control for 24-VDC motor used for remote positioning of an-

tenna. Circuit will operate with supply ranging from 15 to 28 VDC. Offset null controls for opamps use 10K pots. Article describes operation and adjustment of circuit in detail. —D. J.

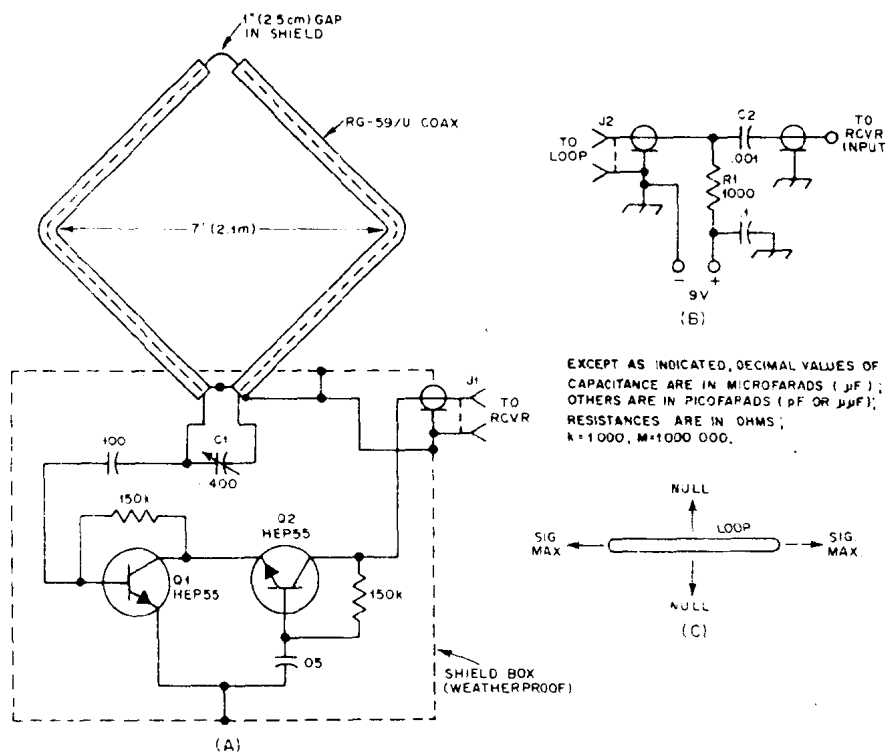
Telfer, An Aerial Rotator Servo, *Wireless World*, April 1975, p 177–181.



DVM FOR SWR—Converts voltage output from analog computer to drive for 3-digit LED display of standing-wave ratio. Circuit uses Precision Monolithics D/A converter A1MDAC-100CC-Q1.

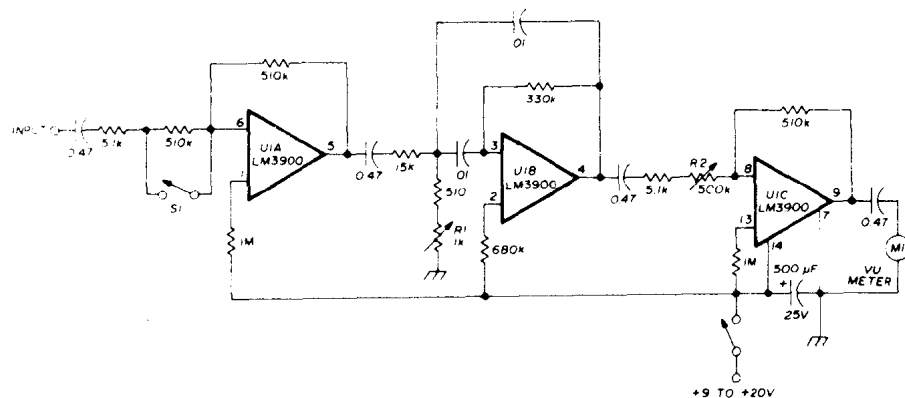
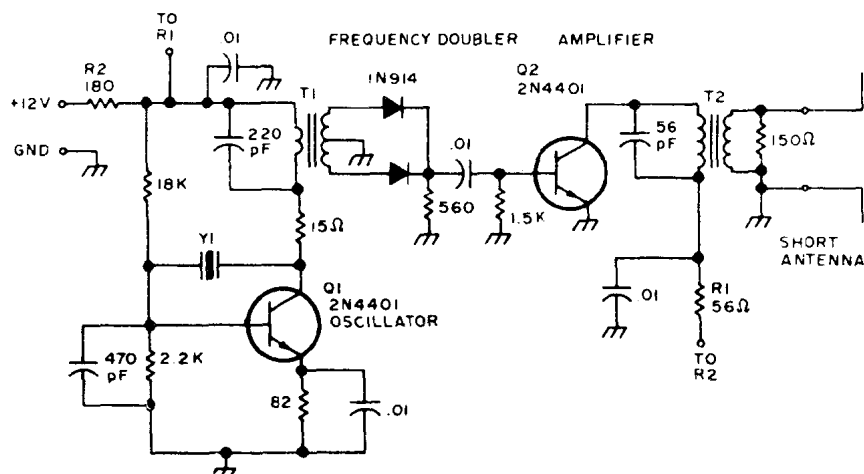
Requires regulated 5-VDC logic supply at 1 A for digital display, along with ± 15 V supplies for logic. Article gives alignment procedure. Accu-

racy of digital reading is better than 0.1% over 0-8 V range.—T. Mayhugh, *The Automatic SWR Computer*, 73 *Magazine*, Dec. 1974, p 86-87.

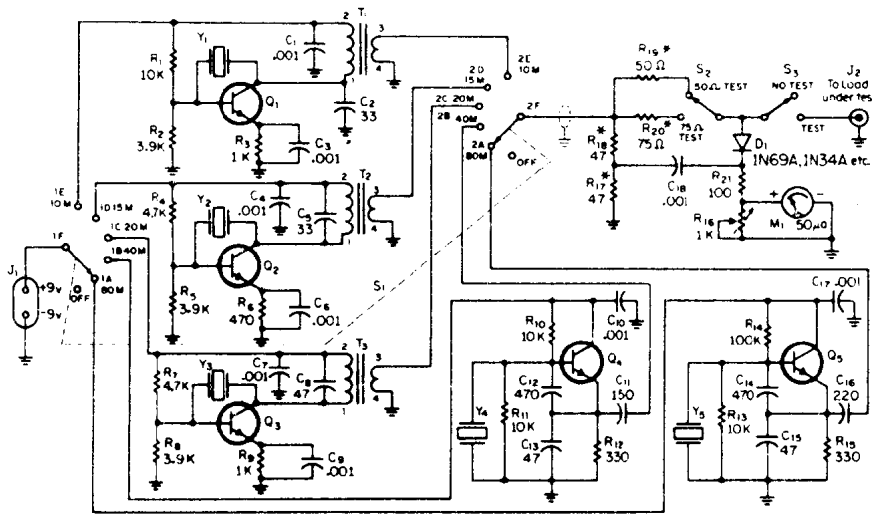


160-METER LOOP-PREAMP—Shielded 5-foot square loop and single preamp pull signals out of noise when propagation conditions make other antennas unsatisfactory. Operating voltage is supplied through coax feeder. R1 isolates signal energy from ground, and C2 keeps DC voltage out of receiver input. Nulls are off broad side of loop.—B. Boothe, Weak-Signal Reception on 160—Some Antenna Notes, *QST*, June 1977, p 35–39.

FAR-FIELD TRANSMITTER—Provides far-field signal source for tuning Yagi and other beam antennas used on amateur radio frequencies. Q1 is Pierce oscillator operating in fundamental mode of 7.06-MHz crystal to permit field-strength measurements at 14.12, 21.18, and 28.24 MHz for 20-, 15-, and 10-meter bands. Antenna uses two 5-foot lengths of wire connected as dipole. T1 is Amidon core T50-2 with 22 turns on primary and 20 turns center-tapped on secondary. T2 is same core with 22-turn primary and 5-turn secondary.—G. Hinkle, Closed Loop Antenna Tuning, *73 Magazine*, May 1976, p 32–33.

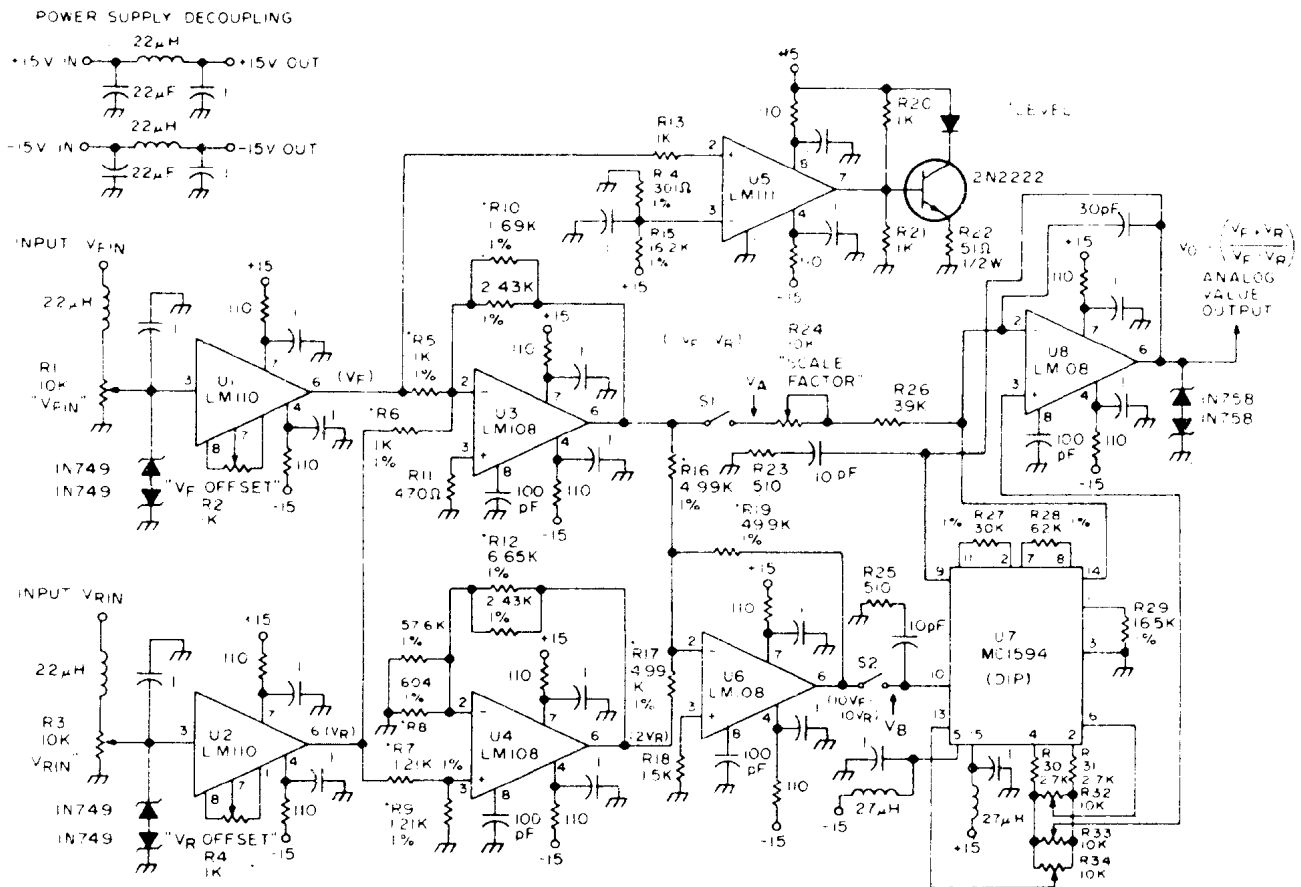


VSWR METER—Simple, easily transported VSWR meter consists of high-gain amplifier, narrow-bandwidth (100-Hz) selective amplifier tuned to 1000 Hz, and variable-gain output amplifier driving low-cost VU meter. Ideal for nulling-type VSWR measurements. Draws only about 6 mA from 9-V transistor battery. Closing S1 increases gain about 100 times for low-level readings. R1 sets U1B to 1000 Hz, while R2 sets reference on VU meter.—J. Reisert, Matching Techniques for VHF/UHF Antennas, *Ham Radio*, July 1976, p 50–56.



SELF-EXCITED SWR BRIDGE—Portable bridge has built-in signal sources for each band from 80 through 10 meters, for tuning antenna on tower before transmission line is connected. Oscillators are crystal controlled at desired antenna tune-up frequencies. Separate oscillators for each band simplify switching problems, so only supply voltage from J₁ and oscillator outputs to meter circuit need be switched. Current drain from 9-V battery is maximum of 12 mA. R₁₇ and R₁₈ should be closely matched, while R₁₁ and R₂₀ should have 5% tolerance.—T. P. Hulick, An S.W.R. Bridge with a Built-In 80 Through 10 Meter Signal Source, *CQ*, June 1971, p 64-66, 68, and 99.

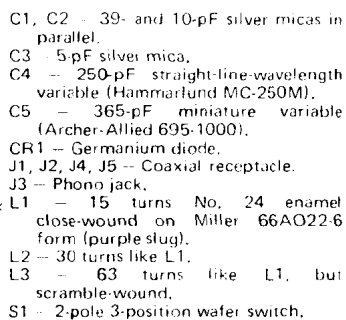
- Q₁-Q₃—RCA 40245.
 S₁—2 pole 6 position subminiature rotary switch. (Centerlab PA-2005).
 S₂—S.p.d.t. slide switch.
 S₃—S.p.s.t. slide switch.
 T₁—Pri.: 11 t. #36 e. Sec.: 3 t. #36 e. on Indiana General CF-101 Q2 toroid.
 T₂—Pri.: 16 t. #36 e. Sec.: 4 t. #36 e. Same core as T₁.
 T₃—Pri.: 20 t. #36 e. Sec.: 5 t. #36 e. Same core as T₁.
 Y₁, Y₂, Y₃—Overtone crystals for 10, 15 and 20 meter bands respectively. HC-6U holders.
 Y₄, Y₅—40 and 80 meter crystals respectively in HC-6U holders.



SWR COMPUTER—Automatically computes standing-wave ratio in 50-ohm coax feeding antenna and delivers analog voltage for driving meter or digital display. Inputs are forward

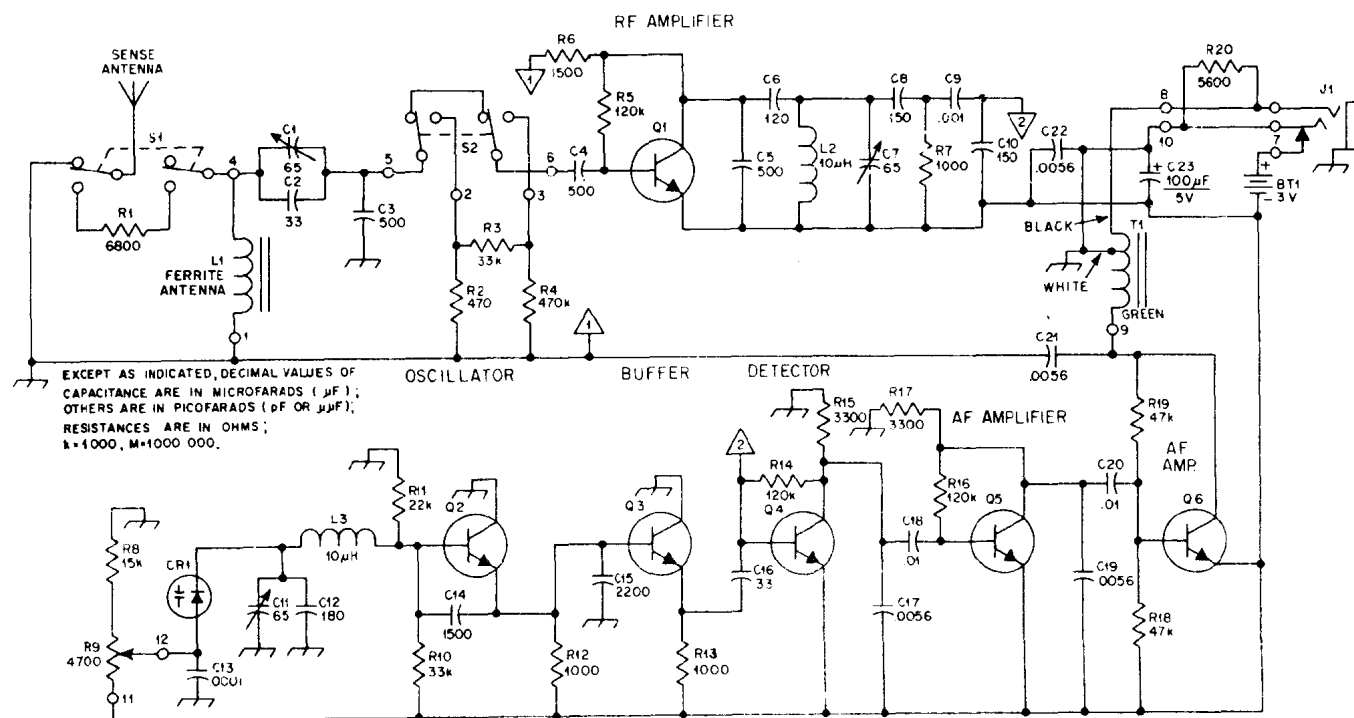
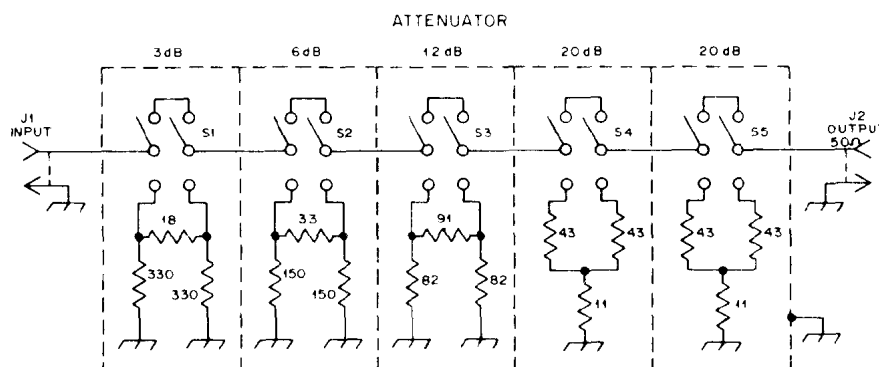
(V_{FIN}) and reverse (V_{RIN}) voltages as conventionally measured for SWR checks. Requires regulated ±15 VDC supply at 40 mA. Article gives construction details and covers adjustment of

critical resistors during alignment.—T. Mayhugh, A Digital SWR Computer!, *73 Magazine*, Nov. 1974, p 80-82, 84, and 86.



RF BRIDGE FOR COAX—Simplifies adjustment of vertical antenna for 40, 80, and 160 meters. S1 in add-on LC unit switches coil for desired band. Values of C1-C4 and standard resistor R1 give range of 10 to 150 ohms for measurement of radiation resistance. Meter can be from 50 to 200 μ A full scale if 500 mW of power is available as signal source. For shorter-wavelength bands, change resistance in parallel with J1 to 5600 ohms and omit C6. L1 for 10 meters should then have 3 1/2 turns No. 18 spaced to occupy 1/4 inch on Miller 4200 coil form. L2 (15 meters) is 6 turns No. 16 enamel closewound on similar form. L3 (20 meters) is 11 turns No. 14 enamel on Miller 66A022-6 form.—J. Sevick, Simple RF Bridges, *QST*, April 1975, p 11–16 and 41.

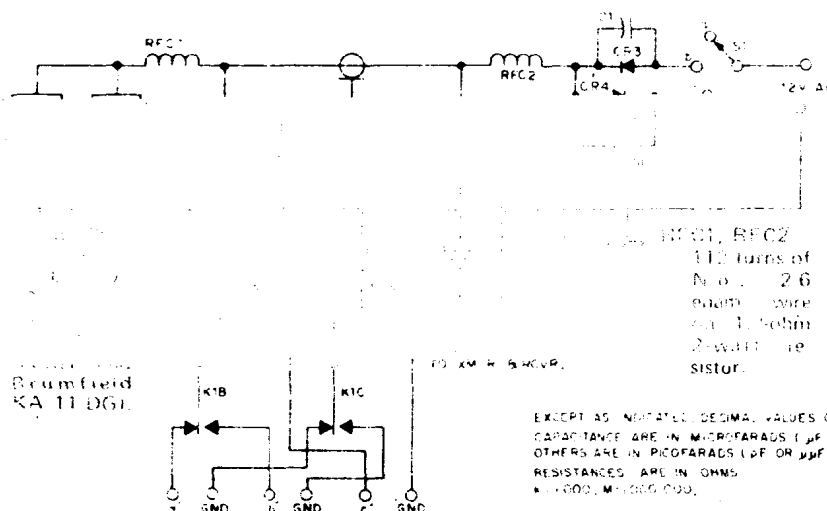
5-STEP ATTENUATOR—Applications include comparing performance of various receiving antennas and measuring gain of preamp used ahead of receiver. Dashed lines represent required shield partitions. All resistors are 1/4-W composition with 5% tolerance.—D. DeMaw, What Does My S-Meter Tell Me?, *QST*, June 1977. □ 40-42.



80-METER DIRECT-CONVERSION—Portable receiver with directional ferrod antenna and vertical sense antenna was developed for radio foxhunting at 1975 Boy Scout World Jamboree in Norway, in competitions for locating four low-power crystal-controlled transmitters hidden along 4-km course. Varactor-tuned oscilla-

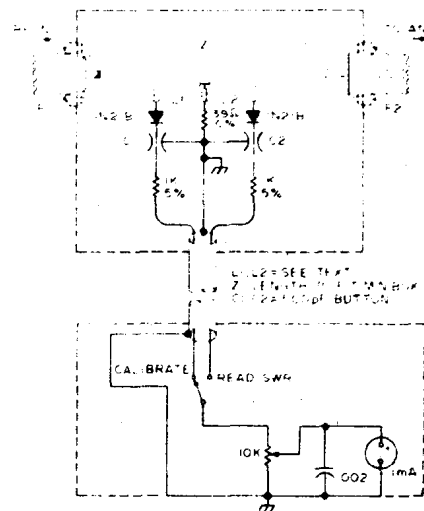
tor provides 20-kHz tuning range with R9, adequate for the frequency used—3.566, 3.585, 3.635, or 3.680 MHz. T1 is subminiature autotransformer with 8-ohm and 2000-ohm sections, for 8-ohm headphones. For high-impedance headphones, connect headphone jack J1

to lug 9 of T1. ON/OFF switch is not needed. L1 is 22 turns No. 28 enamel wound over two 10 × 95 mm ferrite rods taped together. Q1-Q6 are NPN high-frequency small-signal transistors.—N. K. Holter, Radio Foxhunting in Europe, *QST*, Nov. 1976, p 43-46.

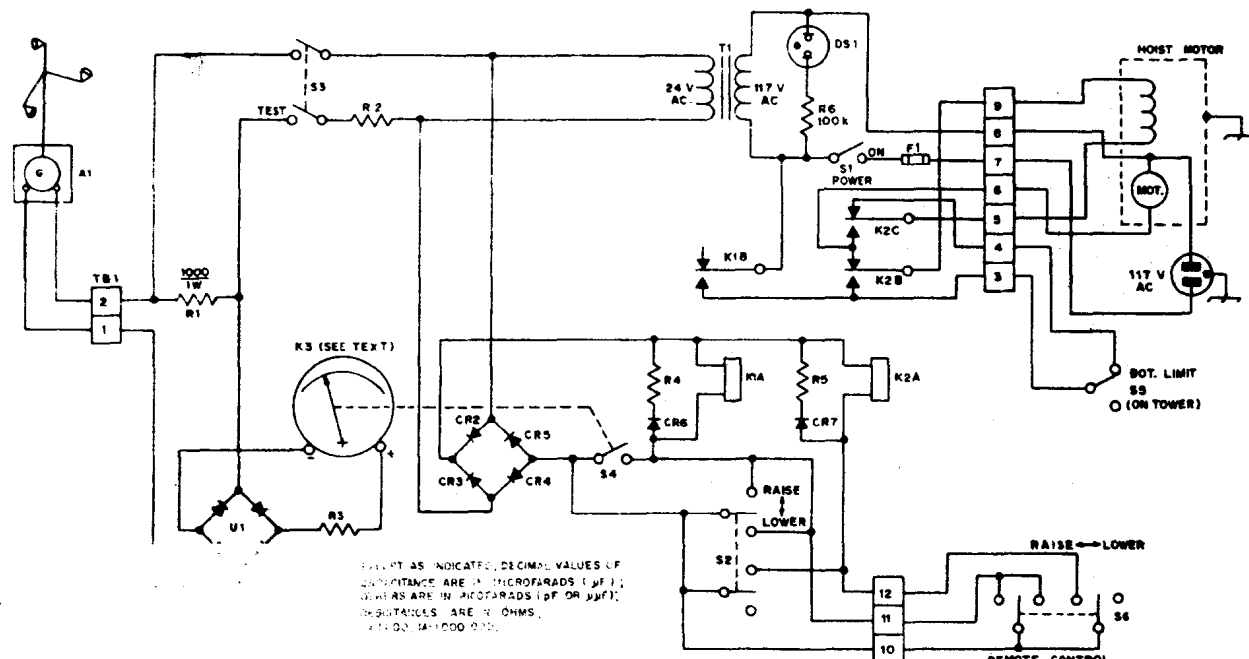


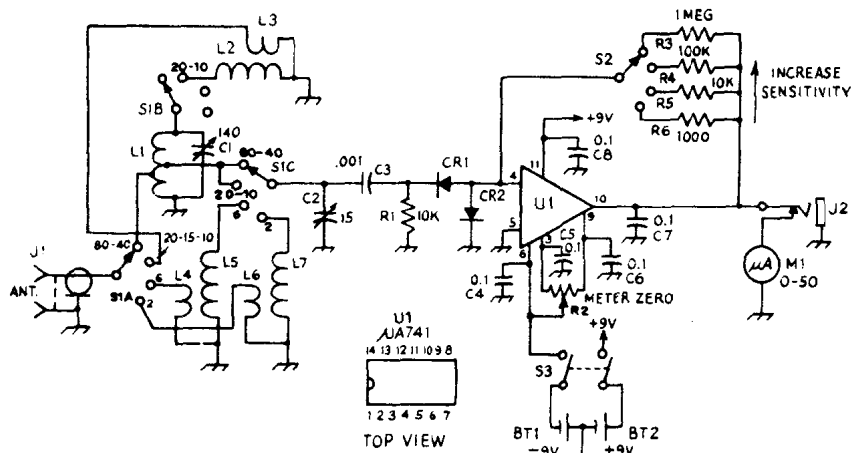
3-ANTENNA REMOTE SWITCHING—Single RF feed line serves for feeding transmitter power to tower and selecting desired one of three antennas. With S1 at a, neither K1 nor K2 is energized. RF energy then passes through cable to antenna terminals a' and GND. In position b,

positive half-waves from 12-VAC supply operate relay K1 through CR1 and CR3, so antenna b' is energized. With S1 at c, K2 is energized through CR4 and CR2 for feeding c'.—U. H. Lambers, A Remote Antenna Switch, *QST*, Aug. 1974, p 41-43.



SWR TO 500 MHz—Permits measuring standing-wave ratio well above limits of many inexpensive indicators. For transmitters up to 2 W, coupling loop L1-L2 can be about 1 inch long. For high-power transmitters, loop length can be reduced to about 1/2 inch.—W. E. Parker, *UHF SWR Indicator*, *73 Magazine*, June 1977, p 68-70.





C1 — 140-pF variable.

C2 — 15-pF variable.

CR1, CR2 — 1N914 or equiv.

L1 — 34 turns No. 24 enam. wound on an Amidon T-68-2 core, tapped 4 turns from ground end.

L2 — 12 turns No. 24 enam. wound on T-68-2 core.

L3 — 2 turns No. 24 wound at ground end of L2.

L4 — 1 turn No. 26 enam. wound at ground end of L5.

L5 — 12 turns No. 26 enam. wound on T-25-12 core.

L6 — 1 turn No. 26 enam.

L7 — 1 turn No. 18 enam. wound on T-25-12 core.

M1 — 50 or 100 μ A dc.

R2 — 10,000-ohm control, linear taper.

S1 — Rotary switch, 3 poles, 5 positions, 3 sections.

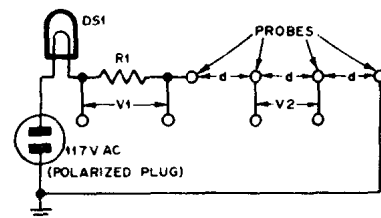
S2 — Rotary switch, 1 pole, 4 positions.

S3 — Dpst Toggle.

U1 — μ A741.

LINEAR FIELD-STRENGTH METER—Has sufficient sensitivity for checking antenna patterns and gain while positioned many wavelengths from antenna. Can be used remotely by connecting external meter at J2. L1 is tuned by C1 for 80 or 40 meters. For 20, 15, or 10 meters, L2 is switched in parallel with L1. L5 and C2 cover

about 40 to 60 MHz, while L7 and C2 cover 130 to 180 MHz. Band-switched circuits avoid use of plug-in inductors. At most sensitive setting of S2, M1 will detect signals from pickup antenna as weak as 100 μ V.—L. McCoy, A Linear Field-Strength Meter, *QST*, Jan. 1973, p 18-20 and 35.



DS1 — 100-watt light bulb.

R1 — 14.6 ohms (5 watt).

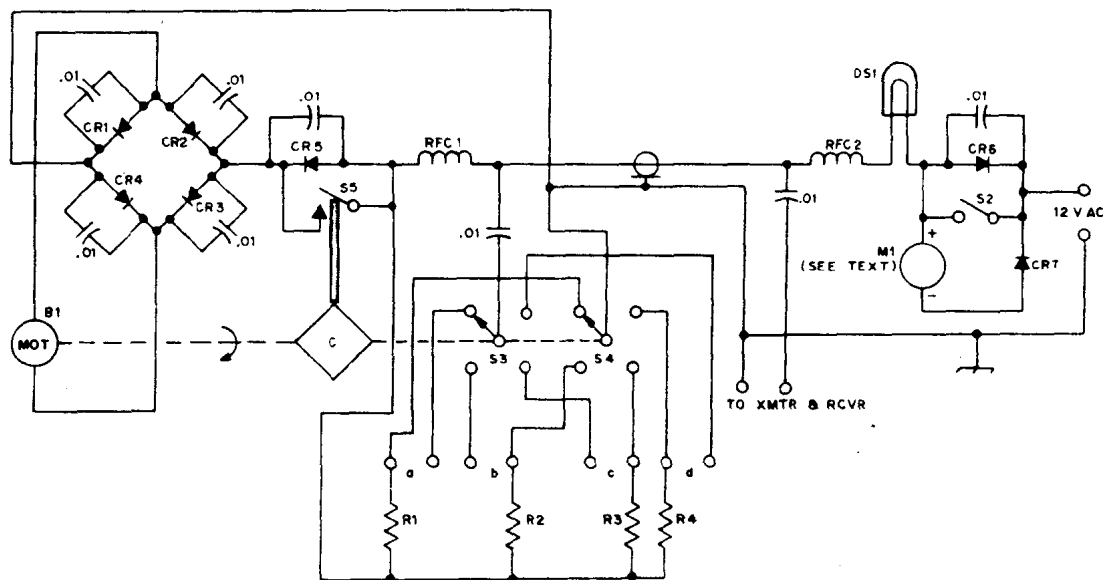
Probes — 5/8-inch dia (iron or copper);

spacing, $d = 18$ inches; penetration depth, $D = 12$ inches.

$$\text{Earth conductivity} = (21) \times \frac{V1}{V2}$$

(millimhos/meter)

EARTH CONDUCTIVITY—Simple AC measurement technique gives 25% accuracy, adequate for siting amateur radio antennas and designing radial ground systems. Measured values will range from 1 to 5 millimhos per meter for poor soil, 10-15 for average soil or fresh water, 100 for very good soil, and 5000 for salt water.—J. Sevvick, Short Ground-Radial Systems for Short Verticals, *QST*, April 1978, p 30-33.



FOUR-POSITION MOTOR SWITCH—Single RF feed line also carries DC for 3-V permanent magnet DC motor B1 atop antenna tower, driving S3 and S4 for remote switching to antennas a, b, c, and d. Diagram shows switches set for feed to antenna a, with no drive applied to B1 since cam C has opened microswitch S5. CR5 and CR6 are now connected in series with opposite polarity, so neither positive nor negative half-waves from 12-VAC supply can drive motor. If

S2 is closed, positive half-waves start B1. Once started, motor runs until cam opens S5; if S2 has not yet been released, motor continues running on positive and negative half-waves. Diode bridge CR1-CR4 makes motor rotate in only one direction for either drive polarity. If S2 is released, before S5 opens, motor stops. 6-V 1-A lamp DS1 comes on dimly when S2 is closed and brightens when S5 closes. If S2 is released

now, B1 drives to next position and stops. If S2 is held down, switching continues. Meter M1 and CR7 identify position of switch. R1-R4, in range of 1K to 10K, are chosen to give 1/4, 1/2, 3/4, and full deflection of meter. Motor drives switch through 2860:1 reduction gears taken from alarm clock. All diodes are 50-PIV 1-A silicon such as 1N4001.—U. H. Lammers, A Remote Antenna Switch, *QST*, Aug. 1974, p 41-43.